MITSUBISHI <INTELLIGENT POWER MODULES>

PM300CL1A060

FLAT-BASE TYPE INSULATED PACKAGE



APPLICATION

General purpose inverter, servo drives and other motor controls





November 2012

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MAXIMUM RATINGS (Tj = 25° C, unless otherwise noted) **INVERTER PART**

Symbol	Parameter	Condition	Ratings	Unit
VCES	Collector-Emitter Voltage	VD = 15V, VCIN = 15V	600	V
±Iс	Collector Current	$Tc = 25^{\circ}C$ (Note-1)	300	A
±IСР	Collector Current (Peak)	Tc = 25°C	600	A
Pc	Collector Dissipation	$Tc = 25^{\circ}C$ (Note-1)	833	W
Tj	Junction Temperature		-20 ~ +150	°C

*: Tc measurement point is just under the chip.

CONTROL PART

Symbol	Parameter	Condition	Ratings	Unit
VD	Supply Voltage	Applied between : VUP1-VUPC, VVP1-VVPC VWP1-VWPC, VN1-VNC	20	V
VCIN	Input Voltage	Applied between : UP-VUPC, VP-VVPC, WP-VWPC UN • VN • WN-VNC	20	V
VFO	Fault Output Supply Voltage	Applied between : UFO-VUPC, VFO-VVPC, WFO-VWPC FO-VNC	20	V
IFO	Fault Output Current	Sink current at UFO, VFO, WFO, FO terminals	20	mA



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TOTAL SYSTEM

Symbol	Parameter	Conditions	Ratings	Unit
V _{CC(PROT)}	Supply Voltage Protected by SC	$V_D = 13.5V \sim 16.5V$ Inverter Part, T _i =+125°C Start	400	V
V _{CC(surge)}	Supply Voltage (Surge)	Applied between : P-N, Surge value	500	V
T _{stg}	Storage Temperature		-40 ~ +125	°C
V _{iso}	Isolation Voltage	60Hz, Sinusoidal, Charged part to Base plate, AC 1min, RMS	2500	V

 $^{\ast:}$ T_c measurement point is just under the chip.

THERMAL RESISTANCE

Symbol	Parameter	Conditions		Limits	Limits	
Symbol	i alametei			Тур.	Max.	
R _{th(j-c)Q}	Thermal Resistance	Inverter, IGBT (per 1 element) (Note.1)	-	-	0.15	
R _{th(j-c)F}		Inverter, FWDi (per 1 element) (Note.1)	-	-	0.23	°C/W
R _{th(c,f)}	Contact Thermal Resistance	Case to fin, (per 1 module)		0.023	0/11	
(1(0-1)		Thermal grease applied (Note.1)			0.020	



* "350G" is printed on the label

ELECTRICAL CHARACTERISTICS (Tj = 25°C, unless otherwise noted) **INVERTER PART**

Symbol	Parameter	Conditions			Limits	-	Linit	
Symbol	i arameter	Conditions	Conditions		Тур.	Max.	Offic	
V	Collector-Emitter Saturation	V _D =15V, I _C =300A	T _j =25°C	-	1.75	2.35	V	
V CE(sat)	Voltage	V _{CIN} =0V, Pulsed (Fig. 1)	Itage V _{CIN} =0V, Pulsed (Fig. 1) T _j =125°C	T _j =125°C	-	1.75	2.35	l v
V _{EC}	FwDi Forward Voltage	-I _C =300A, V _D =15V, V _{CIN} = 15V	(Fig. 2)	-	1.7	2.8	V	
t _{on}				0.3	0.8	2.0		
t _{rr}		$V_D=15V, V_{CIN}=0V \leftrightarrow 15V$	l=0V↔15V	-	0.4	0.8		
t _{c(on)}	Switching Time	$V_{CC}=300V, I_{C}=300A$		-	0.4	1.0	μs	
t _{off}		Inductive Load	(Fig. 3.4)	-	1.0	2.3		
t _{c(off)}			(-	0.3	1.0		
1	Collector-Emitter Cut-off	(1 - 1) $(1 - 1)$ $(1 - 1)$ $(1 - 1)$	Tj=25°C	-	-	1	m۸	
CES	Current	$v_{CE} - v_{CES}$, $v_D - 15v$, $v_{CIN} - 15v$ (Fig.	Tj=125°C	-	-	10	IIIA	



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CONTROL PART

Sumbol	Devementer	Parameter Condition		Limits			Linit
Symbol	Parameter			Min.	Тур.	Max.	Unit
lo	Circuit Current		VN1-VNC	—	6	12	
		VD = 150, VCIN = 150	V*P1-V*PC	_	2	4	
Vth(ON)	Input ON Threshold Voltage	Applied between : UP-VUPC, VP-VVPC,	WP-VWPC	1.2	1.5	1.8	V
Vth(OFF)	Input OFF Threshold Voltage	UN • VN • WN-VNC		1.7	2.0	2.3	v
SC	Short Circuit Trip Level	$-20 \leq T_j \leq 125^\circ C, \ V_D = 15V$	(Fig. 3,6)	600	_		Α
toff(SC)	Short Circuit Current Delay Time	VD = 15V	(Fig. 3,6)		0.2	_	μs
ОТ		Detect Temperature of IGBT chip	Trip level	135	_	_	°C
OT(hys)			Hysteresis	_	20	_	
UV	Supply Circuit Under-Voltage	20 < T; < 125°C	Trip level	11.5	12.0	12.5	v
UVr	Protection	-20 ≤ 1j ≤ 125 C	Reset level	_	12.5	_	
IFO(H)	- Fault Output Current		(Note-2)		—	0.01	m۸
IFO(L)				_	10	15	
tFO	Minimum Fault Output Pulse Width	VD = 15V	(Note-2)	1.0	1.8	_	ms

(Note-2) Fault output is given only when the internal SC, OT & UV protections schemes of either upper or lower arm device operate to protect it.

MECHANICAL RATINGS AND CHARACTERISTICS

	D	Condition		Limits			Linit
Symbol	Parameter			Min.	Тур.	Max.	Unit
_	Mounting torque	Mounting part	screw : M5	2.5	3.0	3.5	N • m
		Main terminal part	screw : M5	2.5	3.0	3.5	
_	Weight	—		_	800	—	g

RECOMMENDED CONDITIONS FOR USE

Symbol	Parameter	Condition	Recommended value	Unit
Vcc	Supply Voltage	Applied across P-N terminals	≤ 400	V
VD	Control Supply Voltage	Applied between : VUP1-VUPC, VVP1-VVPC VWP1-VWPC, VN1-VNC (Note-3)	15.0 ± 1.5	V
VCIN(ON)	Input ON Voltage	Applied between : UP-VUPC, VP-VVPC, WP-VWPC	≤ 0.8	V
VCIN(OFF)	Input OFF Voltage	UN • VN • WN-VNC	≥ 9.0	v
fpwm	PWM Input Frequency	Using Application Circuit of Fig. 8	≤ 20	kHz
tdead	Arm Shoot-through Blocking Time	For IPM's each input signals (Fig. 7)	≥ 2.0	μs

(Note-3) With ripple satisfying the following conditions: dv/dt swing $\leq\pm5V/\mu s,$ Variation $\leq2V$ peak to peak



GND



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PRECAUTIONS FOR TESTING

- Before applying any control supply voltage (VD), the input terminals should be pulled up by resistors, etc. to their corresponding supply voltage and each input signal should be kept off state.
- After this, the specified ON and OFF level setting for each input signal should be done. 2. When performing "SC" tests, the turn-off surge voltage spike at the corresponding protection operation
- 2. When performing "SC" tests, the turn-off surge voltage spike at the corresponding protection operation should not be allowed to rise above VCEs rating of the device.

(These test should not be done by using a curve tracer or its equivalent.)







Fig. 4 Switching time test waveform

Short Circuit Current

SC Trip

Constant Current

toff(SC)

Fig. 6 SC test waveform







1.5V: Input on threshold voltage Vth(on) typical value, 2V: Input off threshold voltage Vth(off) typical value

Fig. 7 Dead time measurement point example



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Fig. 8 Application Example Circuit

NOTES FOR STABLE AND SAFE OPERATION ;

- Design the PCB pattern to minimize wiring length between opto-coupler and IPM's input terminal, and also to minimize the stray capacity between the input and output wirings of opto-coupler.
- •Connect low impedance capacitor between the Vcc and GND terminal of each fast switching opto-coupler.
- Fast switching opto-couplers: tPLH, tPHL $\leq 0.8 \mu$ s, Use High CMR type.
- Slow switching opto-coupler: CTR > 100%
- •Use 4 isolated control power supplies (VD). Also, care should be taken to minimize the instantaneous voltage charge of the power supply.
- •Make inductance of DC bus line as small as possible, and minimize surge voltage using snubber capacitor between P and N terminal.
- •Use line noise filter capacitor (ex. 4.7nF) between each input AC line and ground to reject common-mode noise from AC line and improve noise immunity of the system.



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PERFORMANCE CURVES

November 2012

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SWITCHING RECOVERY LOSS CHARACTERISTICS (TYPICAL)



COLLECTOR REVERSE CURRENT -Ic (A)





COLLECTOR REVERSE CURRENT -Ic (A)

ID VS. fc CHARACTERISTICS (TYPICAL)



SC TRIP LEVEL VS. Tj CHARACTERISTICS (TYPICAL)





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TIME t (sec)



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